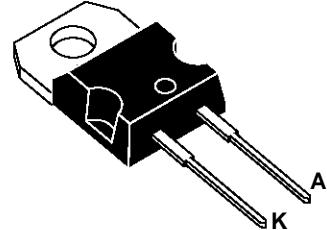


## FAST RECOVERY RECTIFIER DIODES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING

Cathode connected to case



**TO220AC**  
(Plastic)

### SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S

### ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter		Value		Unit
$I_{F\text{RM}}$	Repetitive Peak Forward Current		$t_p \leq 10\mu\text{s}$		130
$I_F$ (RMS)	RMS Forward Current		16		A
$I_F$ (AV)	Average Forward Current		$T_{\text{case}} = 120^\circ\text{C}$ $\delta = 0.5$		8
$I_{F\text{SM}}$	Surge non Repetitive Forward Current		$t_p = 10\text{ms}$ Sinusoidal		100
P	Power Dissipation		$T_{\text{case}} = 100^\circ\text{C}$		20
$T_{\text{stg}}$ $T_j$	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150		°C

Symbol	Parameter	BYT 08P-			Unit
		20	300	400	
$V_{R\text{RM}}$	Repetitive Peak Reverse Voltage	200	300	400	V
$V_{R\text{SM}}$	Non Repetitive Peak Reverse Voltage	220	330	440	V

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{\text{th}} (j - c)$	Junction-case	2.5	°C/W

## ELECTRICAL CHARACTERISTICS

### STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$I_R$	$T_j = 25^\circ C$	$V_R = V_{RRM}$			15	$\mu A$
	$T_j = 100^\circ C$				2.5	mA
$V_F$	$T_j = 25^\circ C$	$I_F = 8A$			1.5	V
	$T_j = 100^\circ C$				1.4	

### RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$t_{rr}$	$T_j = 25^\circ C$	$I_F = 1A$	$di_F/dt = - 15A/\mu s$	$V_R = 30V$		75	ns
		$I_F = 0.5A$	$I_R = 1A$	$I_{rr} = 0.25A$		35	

### TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$t_{IRM}$	$di_F/dt = - 32A/\mu s$	$V_{CC} = 200 V$ $I_F = 8A$ $di_F/dt = - 64A/\mu s$ $L_p \leq 0.05\mu H$ $T_j = 100^\circ C$ See Figure 11			75	ns
				50		
$I_{RM}$	$di_F/dt = - 32A/\mu s$				2.2	A
	$di_F/dt = - 64A/\mu s$			2.8		

### TURN-OFF OVERVOLTAGE COEFFICIENT - (With Series Inductance)

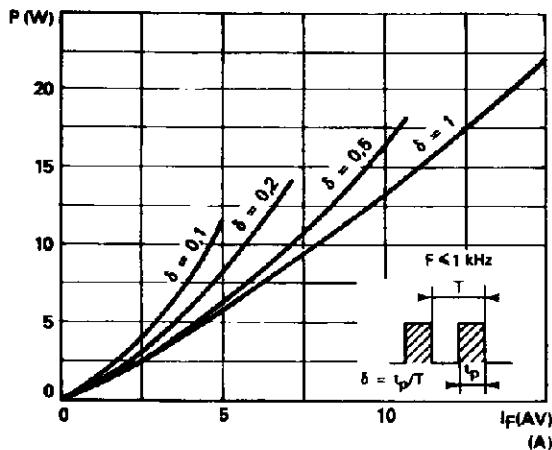
Symbol	Test Condition s			Min.	Typ.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^\circ C$ $di_F/dt = - 8A/\mu s$	$V_{CC} = 120V$ $L_p = 9\mu H$	$I_F = I_{F(AV)}$ See note See figure 12		3.3		

Note: Applicable to BYT 08 P-400 only

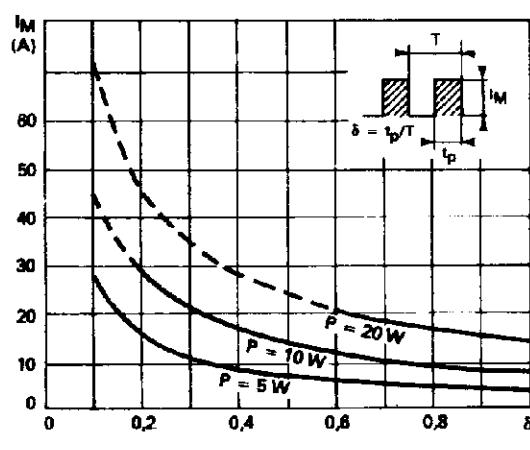
To evaluate the conduction losses use the following equations:

$$V_F = 1.1 + 0.024I_F \quad P = 1.1 \times I_{F(AV)} + 0.024 I_F^2(RMS)$$

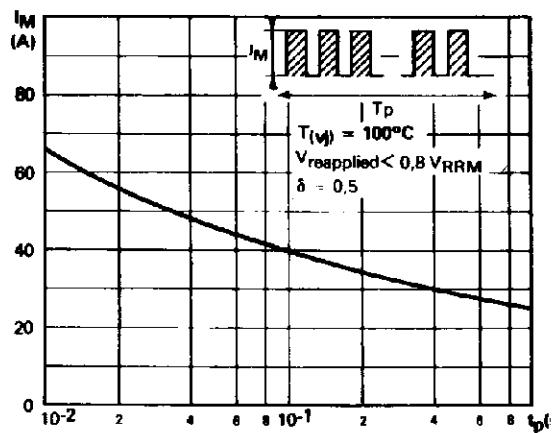
**Figure 1. Low frequency power losses versus average current**



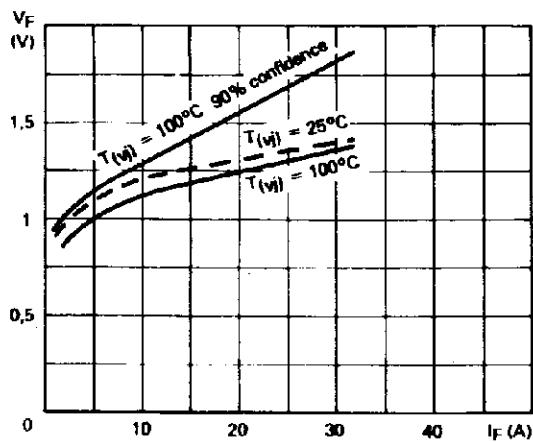
**Figure 2. Peak current versus form factor**



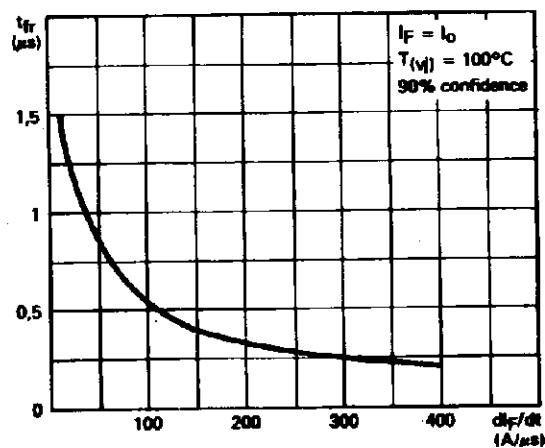
**Figure 3. Non repetitive peak surge current versus overload duration**



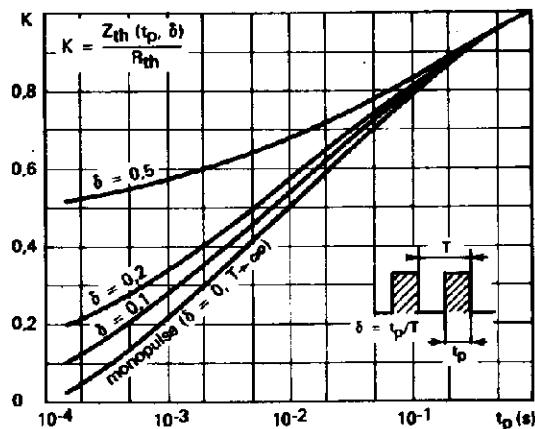
**Figure 5. Voltage drop versus forward current**



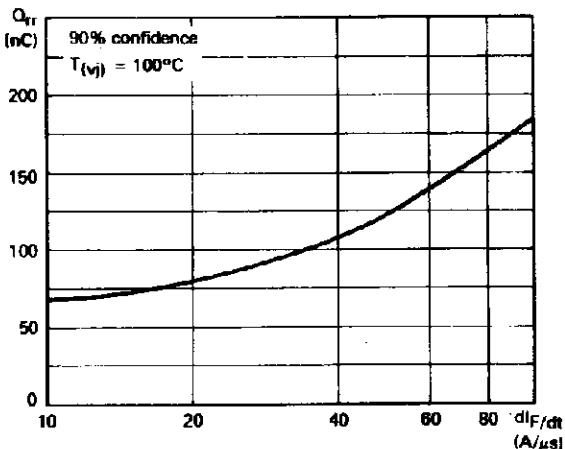
**Figure 7. Recovery time versus  $di_F/dt$**



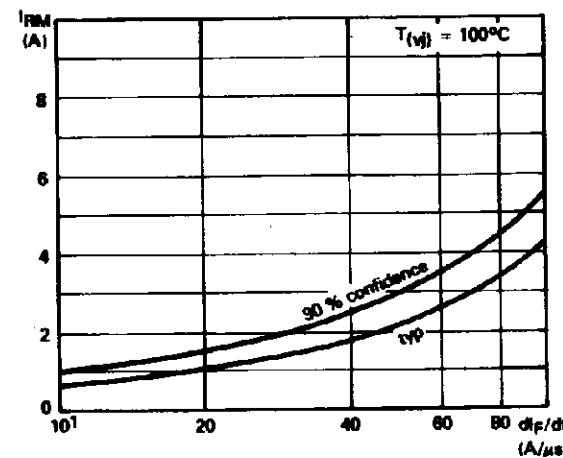
**Figure 4. Thermal impedance versus pulse width**



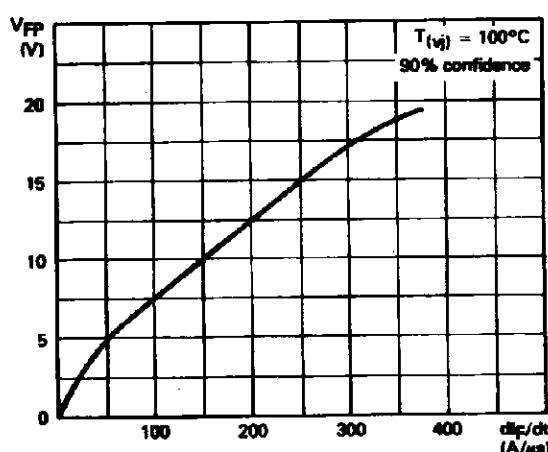
**Figure 6. Recovery charge versus  $di_F/dt$**



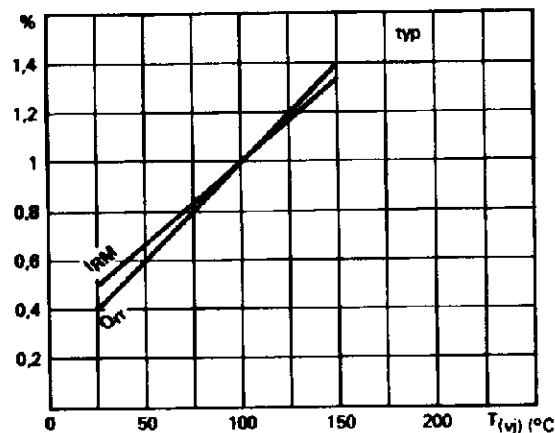
**Figure 8. Peak reverse current versus  $di_F/dt$**



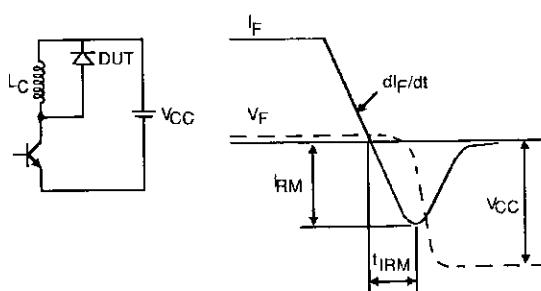
**Figure 9. Peak forward voltage versus  $dI_F/dt$ .**



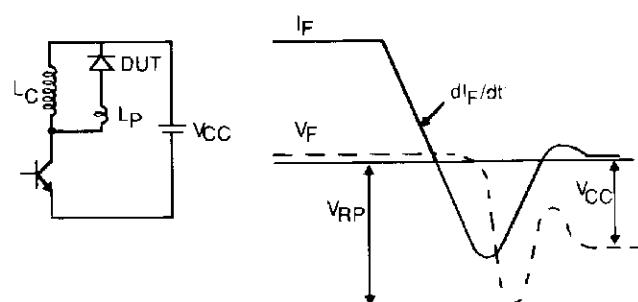
**Figure 10. Dynamic parameters versus junction temperature.**



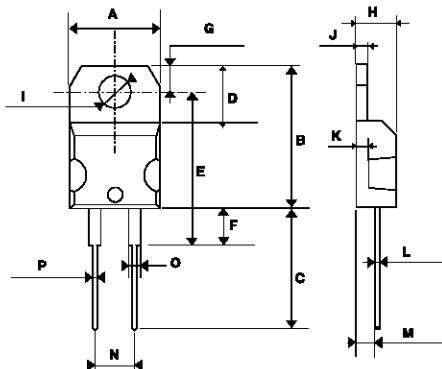
**Figure 11. Turn-off switching characteristics (without series inductance).**



**Figure 12. Turn-off switching characteristics (with series inductance).**



## PACKAGE MECHANICAL DATA TO220AC Plastic



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	10.0	10.4	0.393	0.409
B	15.2	15.9	0.598	0.626
C	13	14	0.511	0.551
D	6.2	6.6•••••	0.244	0.260
E	16.4 typ.		0.645 typ.	
F	3.5	4.2	0.137	0.165
G	2.65	2.95	0.104	0.116
H	4.4	4.6	0.173	0.181
I	3.75	3.85	0.147	0.151
J	1.23	1.32	0.048	0.051
K	1.27 typ.		0.050 typ.	
L	0.49	0.70	0.019	0.027
M	2.4	2.72	0.094	0.107
N	4.95	5.15	0.194	0.203
O	1.14	1.70	0.044	0.067
P	0.61	0.88	0.024	0.034

Cooling method: by conduction (method C)

Marking: type number

Weight: 2.42g

Recommended torque value: 80cm. N

Maximum torque value: 100cm. N

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